

Ref #	Hits	Search Query	DBs	Default Operator	Plurals	Time Stamp
L1	4051	((gate adj dielectric) or (gate adj oxide) or (gate adj insulat\$3)) same (SiON or (silicon adj oxynitride))	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/09/30 13:16
L2	368	L1 same anneal\$3	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/09/30 13:09
L3	78	L2 and ((two or second or twice) near3 anneal\$3)	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/09/30 13:14
L7	11	L1 and (((oxygen near3 free) or (without adj oxygen) or (non adj oxygen) or (no adj2 oxygen)) same anneal\$3)	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/09/30 13:26
L8	77	L3 not L7	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/09/30 13:27